NSN 5961-01-149-9417

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-149-9417 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.140 inches and 0.180 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.056 inches and 0.075 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 regulator voltage and 50.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 200.00 milliamperes forward current, total rms megahertz **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 insulated wire lead **Specification Data:** 81349-mil-s-19500/231 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No